

2SB0946 (2SB946)

Silicon PNP epitaxial planar type

For power switching

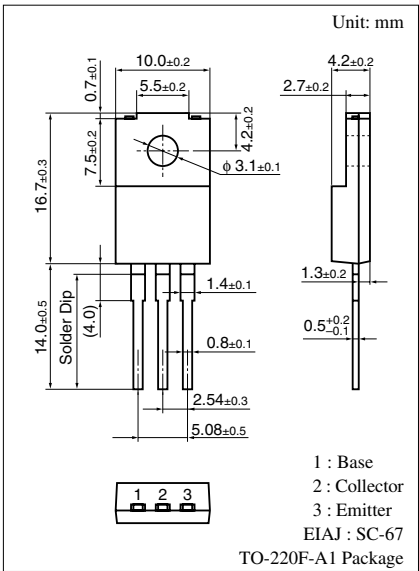
Complementary to 2SD1271

■ Features

- Low collector to emitter saturation voltage $V_{CE(sat)}$
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter		Symbol	Rating	Unit
Collector to base voltage		V_{CBO}	−130	V
Collector to emitter voltage		V_{CEO}	−80	V
Emitter to base voltage		V_{EBO}	−7	V
Peak collector current		I_{CP}	−15	A
Collector current		I_C	−7	A
Collector power dissipation	$T_C = 25^{\circ}\text{C}$	P_C	40	W
	$T_a = 25^{\circ}\text{C}$		2	
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature		T_{stg}	−55 to +150	$^{\circ}\text{C}$



■ Electrical Characteristics $T_C = 25^\circ\text{C}$

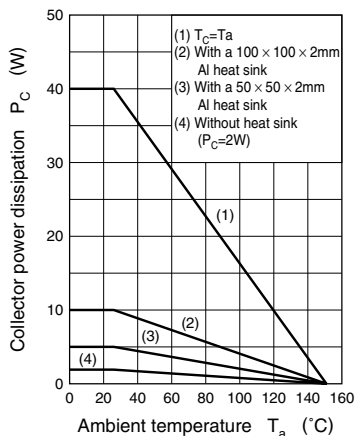
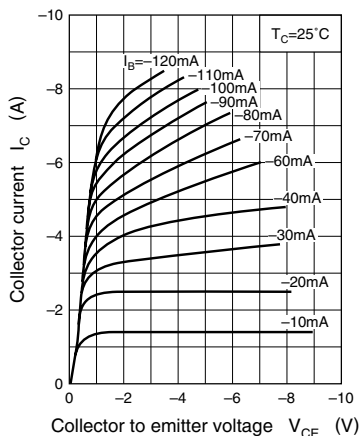
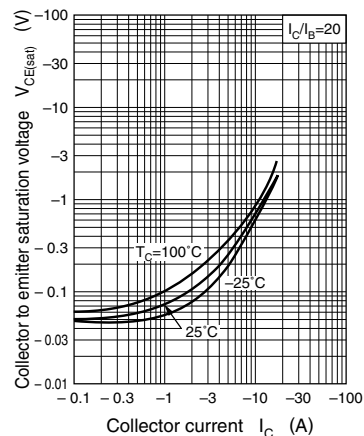
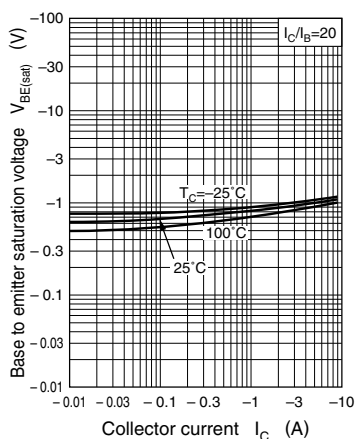
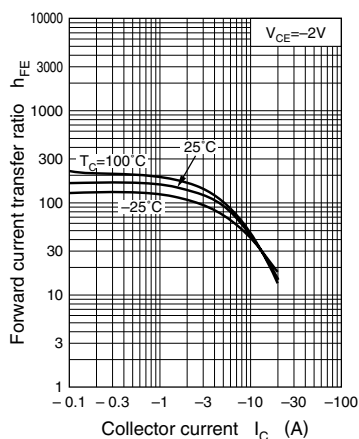
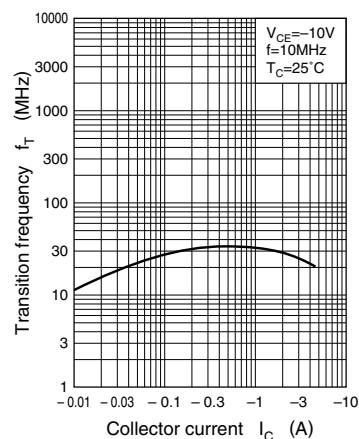
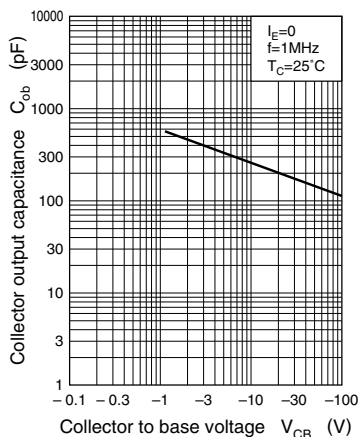
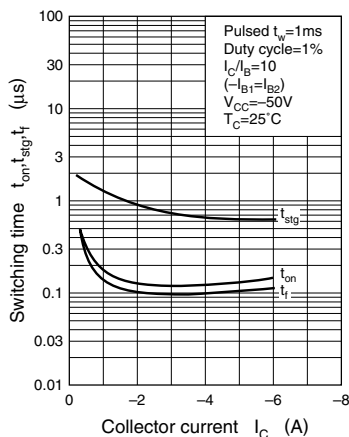
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -100\text{ V}, I_E = 0$			-10	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$			-50	μA
Collector to emitter voltage	V_{CEO}	$I_C = -10\text{ mA}, I_B = 0$	-80			V
Forward current transfer ratio	h_{FE1}	$V_{CE} = -2\text{ V}, I_C = -0.1\text{ A}$	45			
	h_{FE2}^*	$V_{CE} = -2\text{ V}, I_C = -3\text{ A}$	90		260	
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -5\text{ A}, I_B = -0.25\text{ A}$			-0.5	V
Base to emitter saturation voltage	$V_{BE(sat)}$	$I_C = -5\text{ A}, I_B = -0.25\text{ A}$			-1.5	V
Transition frequency	f_T	$V_{CE} = -10\text{ V}, I_C = -0.5\text{ A}, f = 10\text{ MHz}$		30		MHz
Turn-on time	t_{on}	$I_C = -3\text{ A}, I_{B1} = -0.3\text{ A}, I_{B2} = 0.3\text{ A}$		0.5		μs
Storage time	t_{stg}			1.5		μs
Fall time	t_f			0.1		μs

Note) *: Rank classification

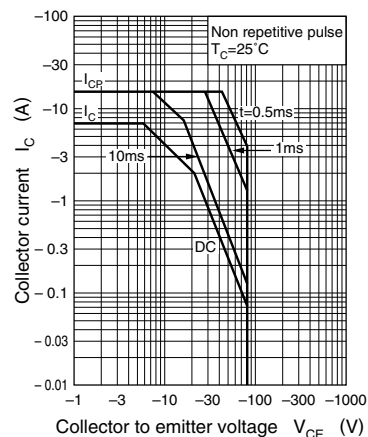
Rank	Q	P
h_{FE2}	90 to 180	130 to 260

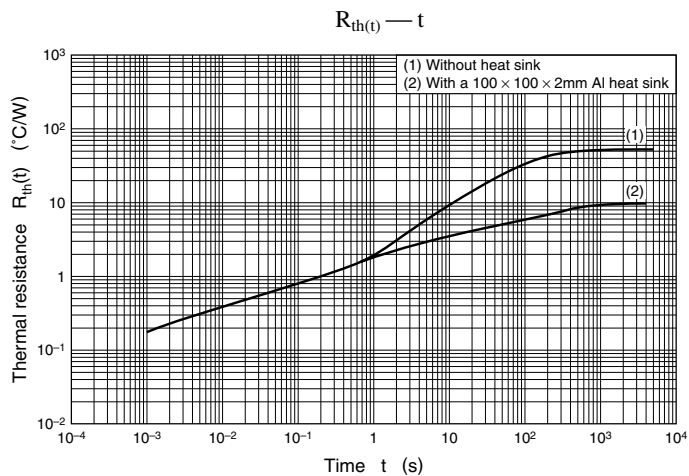
Ordering can be made by the common rank (PQ rank $h_{FE2} = 90$ to 260) in the rank classification.

Note.) The Part number in the Parenthesis shows conventional part number.

$P_C - T_a$  $I_C - V_{CE}$  $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_C$  $C_{ob} - I_C$  $t_{on}, t_{stg}, t_f - I_C$ 

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